Supporting Information

Solution processed organic light-emitting diodes using a triazatruxene crosslinkable hole transporting material.

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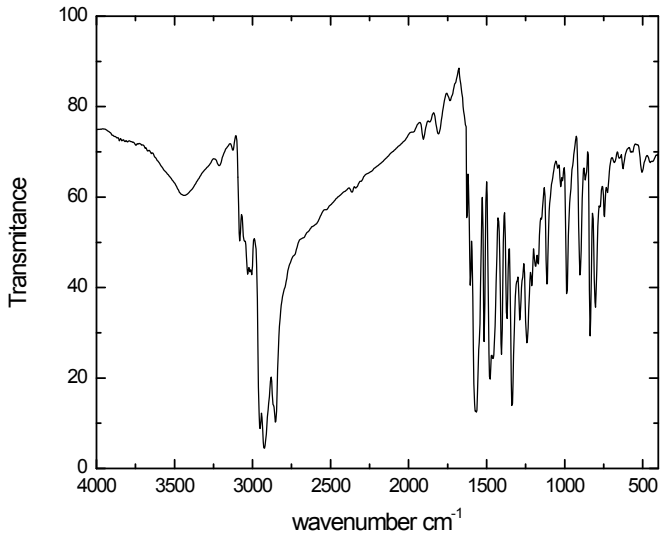

Figure S1. FT-IR spectrum of an as-deposited KR386 thin film.

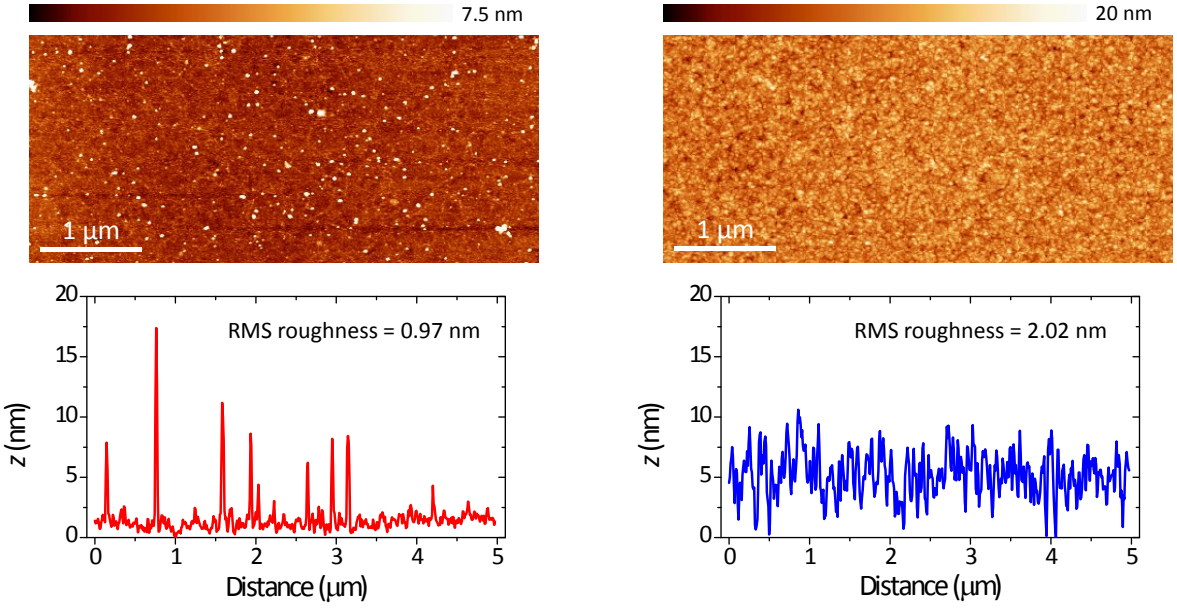

Figure S2. Atomic Force Microscopy analysis for as-deposited KR386 films (Left) and annealed (180 ºC for 15 minutes) KR386 films (Right).

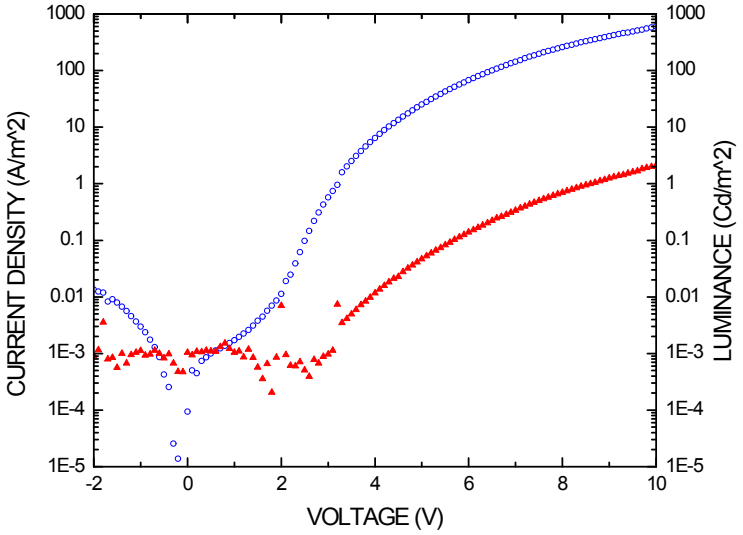

Figure S3. Current density and luminance versus voltage of a KR386 LED with the following device structure; ITO/PEDOT:PSS/KR386/Ba/Ag.